

STC401F

NPN Silicon Transistor

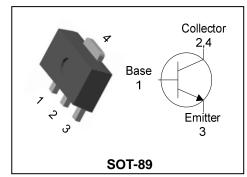
Descriptions

- General purpose amplifier
- High voltage application

Features

- Low saturation switching application
- Voltage regulator application
- Low saturation: $V_{CE}(sat) = 0.4V typ$
- ullet High voltage : $V_{\text{CEO}} = 60 V$ Min

PIN Connection



Ordering Information

Type No.	Marking	Package Code
STC401F	C401 YWW	SOT-89

C401: DEVICE CODE, YWW(Y: Year code, WW: Weekly code)

Absolute maximum ratings

(Ta=25°C)

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V_{CBO}	80	V
Collector-Emitter voltage			V
Emitter-base voltage			V
Collector current	I _C	1	А
Collector dissinction	P _C	0.5	\A/
Collector dissipation	P _C *	1	W
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55~150	°C

Charac	cteristic	Symbol	Тур.	Max	Unit
Th	Junction-ambient	$R_{th(J-A)}$	-	250.0	°C /\/\
Thermal resistance		R _{th(J-A)} *	-	125.0	°C/W

^{*:} When mounted on ceramic substrate(250 mm²×0.8t)

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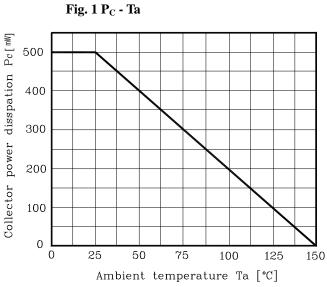
Electrical Characteristics

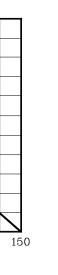
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	BV _{CBO}	$I_C = 100 \mu A, \ I_E = 0$	80	-	-	V
Collector-Emitter breakdown voltage	BV _{CEO}	$I_C=1$ mA, $I_B=0$	60	ı	ı	٧
Emitter-Base breakdown voltage	BV _{EBO}	$I_E=10mA$, $I_C=0$	5	1	1	٧
Collector cut-off current	I _{CBO}	$V_{CB} = 60V, I_{E} = 0$	-	1	0.1	μΑ
Collector cut-off current	I _{CEO}	$V_{CE} = 60V$, $I_{B} = 0$	-	-	0.5	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} =5V, I _C =0	-	1	0.1	μΑ
D0	h _{FE} *	V _{CE} =2V, I _C =100mA	200	-	500	-
DC current gain		V _{CE} =2V, I _C =1A	80	-	-	
Base-Emitter on voltage	V _{BE(ON)}	V _{CE} =2V, I _C =500mA	-	-	1.2	V
Collector-Emitter saturation voltage	V _{CE(sat)}	I _C =500mA, I _B =50mA	_	-	0.4	V
Collector output capacitance	C _{ob}	V _{CB} =10V, I _E =0, f=1MHz	-	10	-	pF
Transition frequency	f _T	V _{CB} =10V, I _C =50mA	-	160	-	MHz

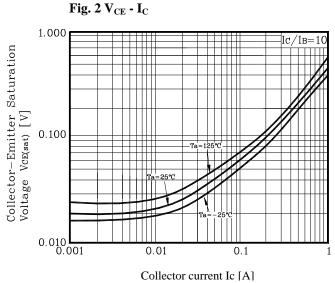
^{*} h_{FE} rank : 200~500 Only

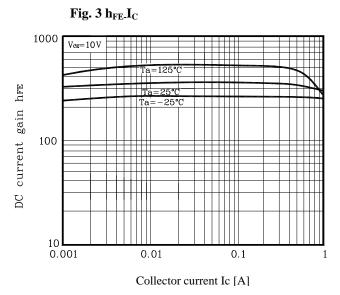
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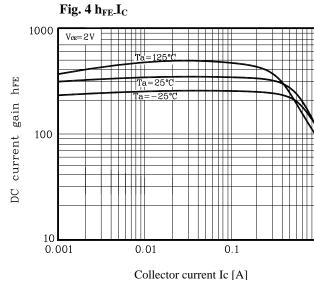
Electrical Characteristic Curves

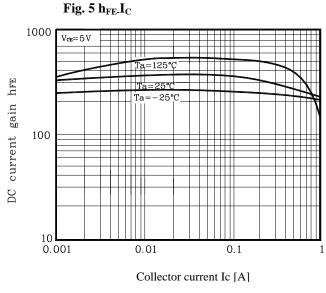


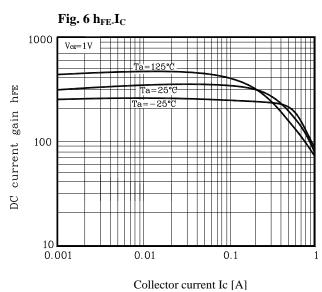












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Electrical Characteristic Curves

Fig. 7 Cob - V_{CB}

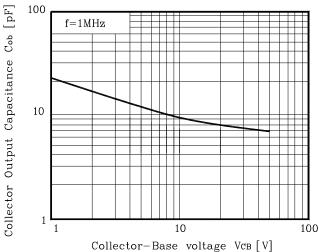


Fig. 8 I_C - V_{CE}

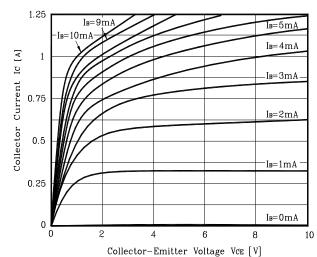


Fig. 9 f_T - I_C

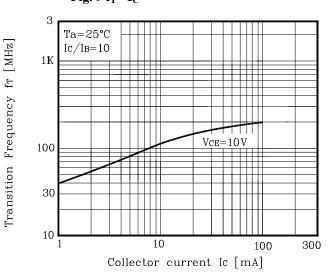
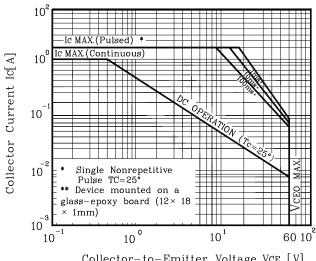
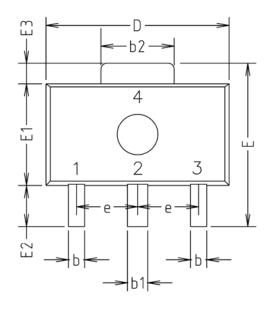


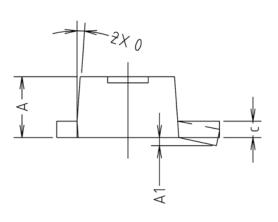
Fig. 10 Safe operating Area



Collector-to-Emitter Voltage VCE [V]

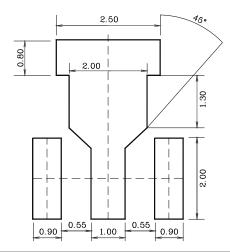
Outline Dimension(mm)





	MILLIMETERS			
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	NOTE
Α	1.40	1.50	1.60	
A1	0.00	_	0.10	
b	0.38	0.42	0.48	
b1	0.48	0.52	0.58	
b2	1.79	1.82	1.87	
С	0.40	0.42	0.46	
D	4.40	4.50	4.70	
Ε	3.70	4.00	4.30	
E1	2.40	2.50	2.70	
E2	0.80	1.00	1.20	
E3	0.40	0.50	0.60	
е		1.50 TYP.		
0		4° TYP.		

* Recommend PCB solder land [Unit: mm]



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